

Thermal Characteristics

Symbol	Parameter	Тур	Max	Units
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case		4.5	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient *		50	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient		110	°C/W

Off Cha	Parameter	Test Conditions	Min	Тур	Max	Units
	ractariation					
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0 V, I _D = 250 μA	60			V
ΔΒV _{DSS} ΔΒV _{DSS} / ΔΤ _J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu\text{A}$, Referenced to 25°C		0.05		V/°C
I _{DSS}	Coemcient	V _{DS} = 60 V, V _{GS} = 0 V			1	μA
'DSS	Zero Gate Voltage Drain Current	$V_{DS} = 48 \text{ V}, T_{C} = 150^{\circ}\text{C}$			10	 μΑ
I _{GSSF}	Gate-Body Leakage Current, Forward	$V_{GS} = 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	$V_{GS} = -20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			-100	nA
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	racteristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.0		2.5	V
R _{DS(on)}	Static Drain-Source	$V_{GS} = 10 \text{ V}, I_D = 5.5 \text{ A}$		0.092	0.115	Ω
0	On-Resistance	$V_{GS} = 5 V, I_D = 5.5 A$ $V_{DS} = 25 V, I_D = 5.5 A$ (Note 4)		0.115	0.145	6
9 _{FS}	Forward Transconductance	$V_{\rm DS} = 25 \text{ V}, \text{ I}_{\rm D} = 5.5 \text{ A}$ (Note 4)		6		S
Dynami	c Characteristics					
C _{iss}	Input Capacitance	V _{DS} = 25 V, V _{GS} = 0 V,		270	350	pF
C _{oss}	Output Capacitance	f = 1.0 MHz		95	125	pF
C _{rss}	Reverse Transfer Capacitance	-		17	23	pF
Switchi	ng Characteristics					
1	ng Characteristics Turn-On Delay Time			8	25	nc
t _{d(on)} t _r	Turn-On Rise Time	V _{DD} = 30 V, I _D = 6.8 A,		90	190	ns
-	Turn-Off Delay Time	$R_{G} = 25 \Omega$		20	50	ns ns
t _{d(off)} t _f	Turn-Off Fall Time	(Note 4, 5)		40	90	ns
Q _g	Total Gate Charge	V _{DS} = 48 V, I _D = 13.6 A,		4.8	6.4	nC
Q _{gs}	Gate-Source Charge	$V_{\rm DS} = 48$ V, $I_{\rm D} = 13.0$ A, $V_{\rm GS} = 5$ V		1.6		nC
Q _{gd}	Gate-Drain Charge	(Note 4, 5)		2.7		nC
I		d Movimum Dotingo				
brain-50	ource Diode Characteristics an Maximum Continuous Drain-Source Dio				11	A
I _{SM}	Maximum Pulsed Drain-Source Diode F				44	A
V _{SD}		$V_{GS} = 0 V, I_S = 11 A$			1.5	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0 V, I _S = 13.6 A,		45		ns
Q _{rr}	Reverse Recovery Charge	$dI_{\rm F}$ / dt = 100 A/µs (Note 4)		45		nC

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